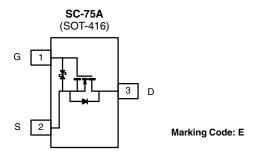




N-Channel 60 V (D-S) MOSFET

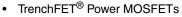
PRODUCT SUMMARY					
V _{DS(min.)} (V)	$R_{DS(on)}(\Omega)$	V _{GS(th)} (V)	I _D (mA)		
60	1.25 at V _{GS} = 10 V	1 to 2.5	330		



Ordering Information: Si1022R-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES





• Low On-Resistance: 1.25 Ω

Low Threshold: 2.5 V

Low Input Capacitance: 30 pFFast Switching Speed: 25 ns

· Low Input and Output Leakage

Miniature Package

ESD Protected: 2000 V

• Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- · Battery Operated Systems
- · Solid State Relays

BENEFITS

- · Low Offset Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Error Voltage
- Small Board Area

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Ocaliana Paris Commula	T _A = 25 °C	l _D	330	mA	
Continuous Drain Current ^a	T _A = 85 °C		240		
Pulsed Drain Current ^a		I _{DM}	650		
Davier Dissipation	T _A = 25 °C	P _D	250	mW	
Power Dissipation ^a	T _A = 85 °C		130	11100	
Thermal Resistance, Maximum Junction-to-Ambient ^a		R _{thJA}	500	°C/W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	

Notes:

a. Surface mounted on FR4 board, power applied for $t \le 10 \text{ s}$.



ROHS COMPLIANT HALOGEN FREE

Vishay Siliconix



SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 10 \mu\text{A}$	60			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 0.25 \text{ mA}$	1		2.5	V	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$			± 150		
Gate-Body Leakage	I _{GSS}	T _J = 85 °C			± 500		
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 20	nA	
		$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}$			10		
Zero Gate Voltage Drain Current	I _{DSS}	T _J = 85 °C			100		
		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ	
On Chata Duain Commanda	lac s	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}$	500			mA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 7.5 \text{ V}, V_{GS} = 10 \text{ V}$	800			IIIA	
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 200 \text{ mA}$			3.0		
Drain Course On State Registeres		T _J = 125 °C			5.0	Ω	
Drain-Source On-State Resistance ^a		$V_{GS} = 10 \text{ V}, I_D = 500 \text{ mA}$			1.25	52	
		T _J = 125 °C			2.25		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 10 \text{ V}, I_{D} = 200 \text{ mA}$	100			mS	
Diode Forward Voltage ^a	V _{SD}	$V_{GS} = 0 \text{ V, } I_{S} = 200 \text{ mA}$			1.3	V	
Dynamic ^b							
Input Capacitance	C _{iss}			30			
Output Capacitance	C _{oss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		6		pF	
Reverse Transfer Capacitance	C _{rss}			2.5			
Gate Charge	Qg	$V_{DS} = 10 \text{ V}, I_D = 250 \text{ mA}, V_{GS} = 4.5 \text{ V}$			0.6	nC	
Switching ^{b, c}							
Turn-On Time	t _(on)	$V_{DD} = 30 \text{ V}, R_L = 150 \Omega,$			25	ns	
Turn-Off Time	t _(off)	$I_D = 200 \text{ mA}, V_{GEN} = 10 \text{ V}, R_g = 10 \Omega$			35	110	

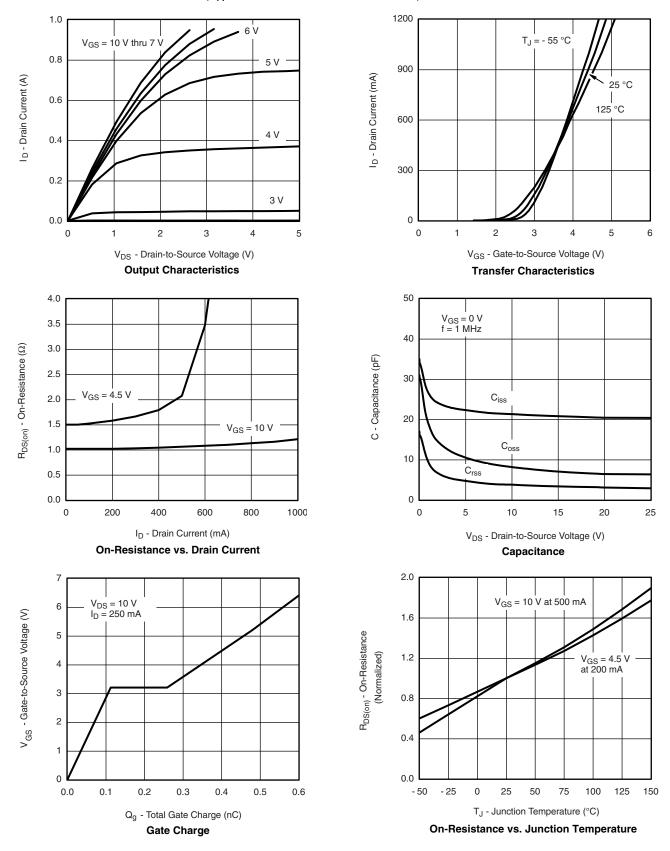
Notes:

- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. For DESIGN AID ONLY, not subject to production testing.
- c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



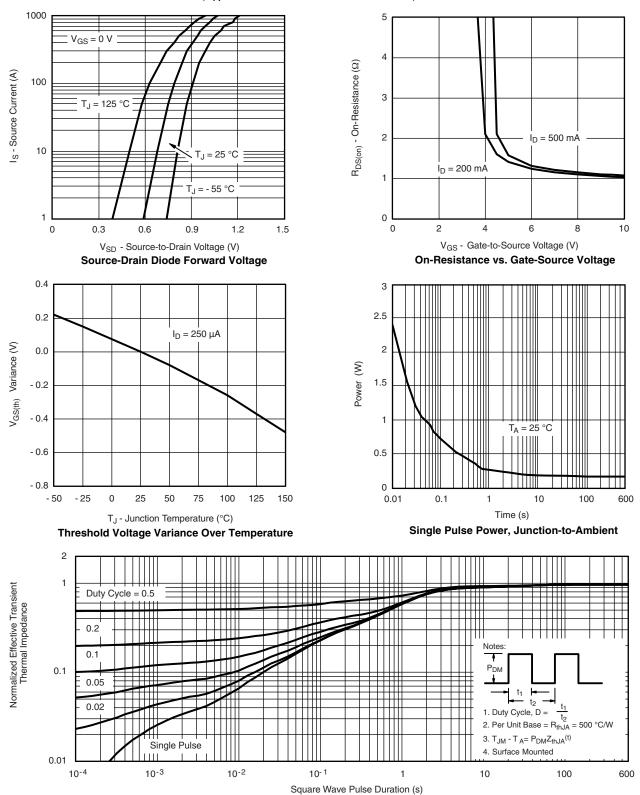
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)



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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

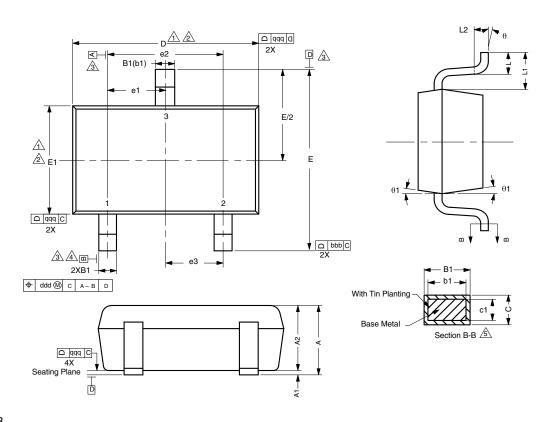


Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71331.



SC-75A: 3 Leads



DWG: 5868

Notes

Dimensions in millimeters will govern.

- Dimension D does not include mold flash, protrusions or gate burrs. Mold flash protrusions or gate burrs shall not exceed 0.10 mm per end. Dimension E1 does not include Interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.10 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.
- ②Datums A, B and D to be determined 0.10 mm from the lead tip.

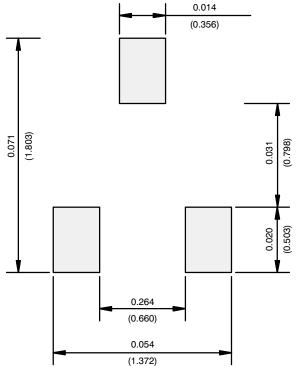
 4\text{Terminal positions are shown for reference only.}
- These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIMENSIONS	TOLERANCES		
aaa	0.10		
bbb	0.10		
ccc	0.10		
ddd	0.10		

DIM.	ı	NOTE		
DIIVI.	MIN.	NOM.	MAX.	NOTE
Α	-	-	0.80	
A1	0.00	-	0.10	
A2	0.65	0.70	0.80	
B1	0.19	-	0.24	5
b1	0.17	0.17 - 0		
С	0.13	-	0.15	5
c1	0.10	-	0.12	5
D	1.48	1.575	1.68	1, 2
E	1.50	1.60	1.70	
E1	0.66	0.76	0.86	1, 2
e1	0.50 BSC			
e2	1.00 BSC			
e3	0.50 BSC			
L	0.15	0.205	0.30	
L1	0.40 ref.			
L2	0.15 BSC			
q	0°	-	8°	
q1	4°	-	10°	



RECOMMENDED MINIMUM PADS FOR SC-75A: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



Legal Disclaimer Notice

Vishay

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000